

P-channel enhancement mode vertical D-MOS transistor

Manufacturers	NXP Semiconductor
Package/Case	SOT223
Product Type	Discrete Semiconductors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for BSP225 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

BSP225 is a power MOSFET transistor that is designed for use in low voltage, high-speed switching applications. Here are some of its features:

Features

- Drain-source voltage (VDS) rating of 60 volts
- Continuous drain current (ID) rating of 8 amperes
- Low on-resistance (RDS(on)) of 0.1 ohms
- Fast switching speed
- TO-220 package for easy mounting

Application

- Power supplies
- DC-DC converters
- Motor control circuits
- Audio amplifiers
- Switching regulators

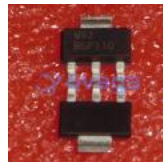


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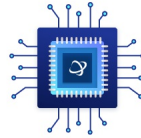
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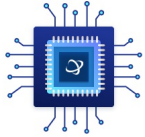
PBSS5350SS

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